NSN 5961-00-114-2647

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-114-2647 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 0.150 inches **Overall Height:** 0.065 inches **Overall Width:** 0.160 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** -20.0 collector to base voltage/static/emitter open all transistor and -20.0 collector to emitter voltage/static/base open all transistor and -4.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 0.7 watts small-signal input power, common-collector 2nd transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: pnp **Test Data Document:** 94756-472-0983 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No